

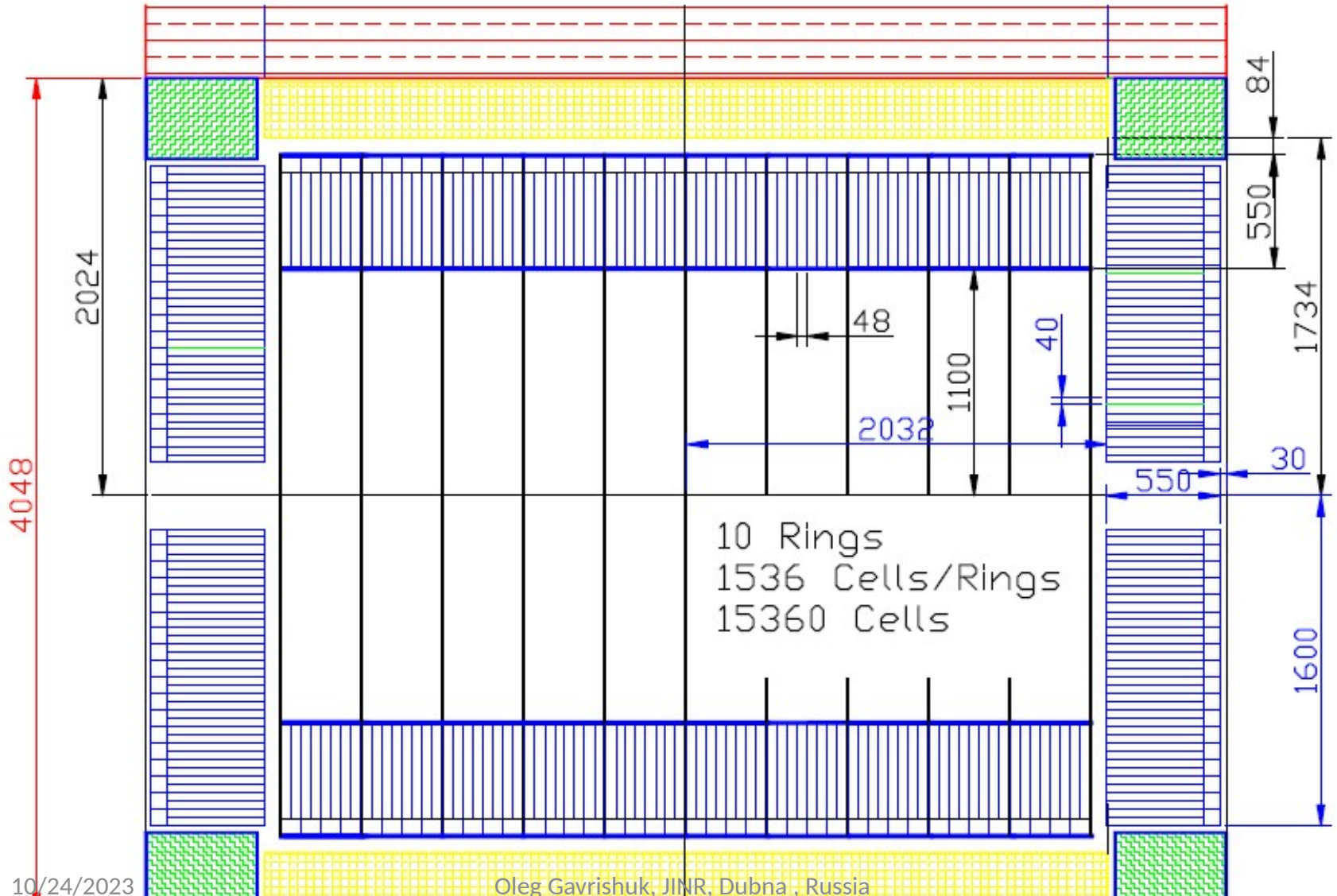
# **SPD ECAL**

## **Status Report 2023**

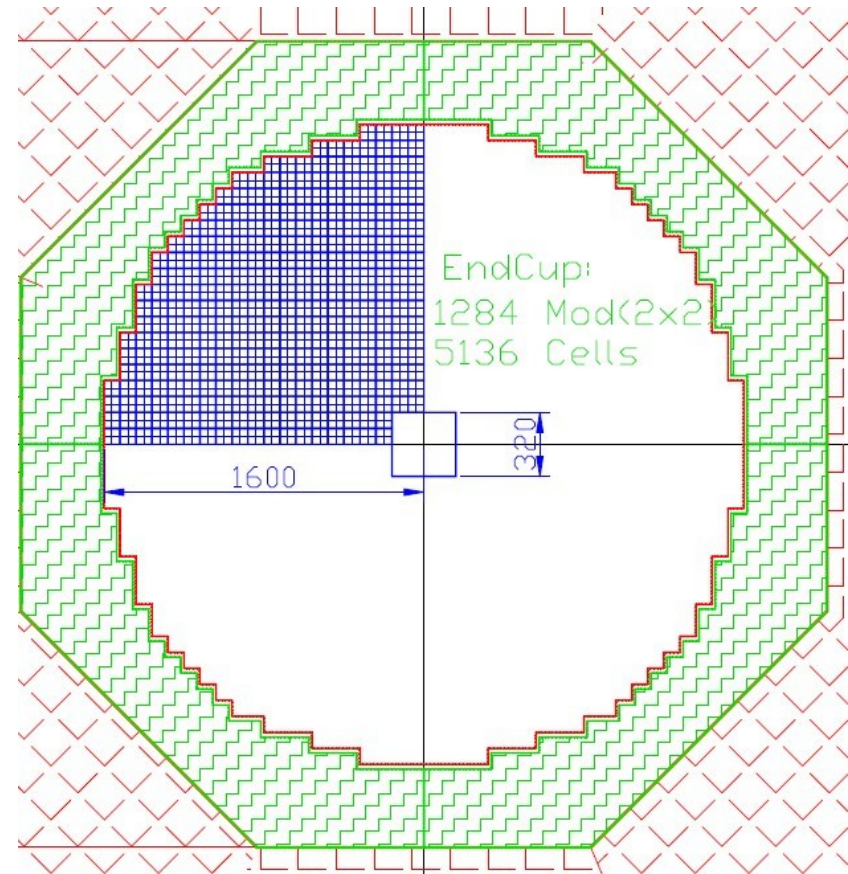
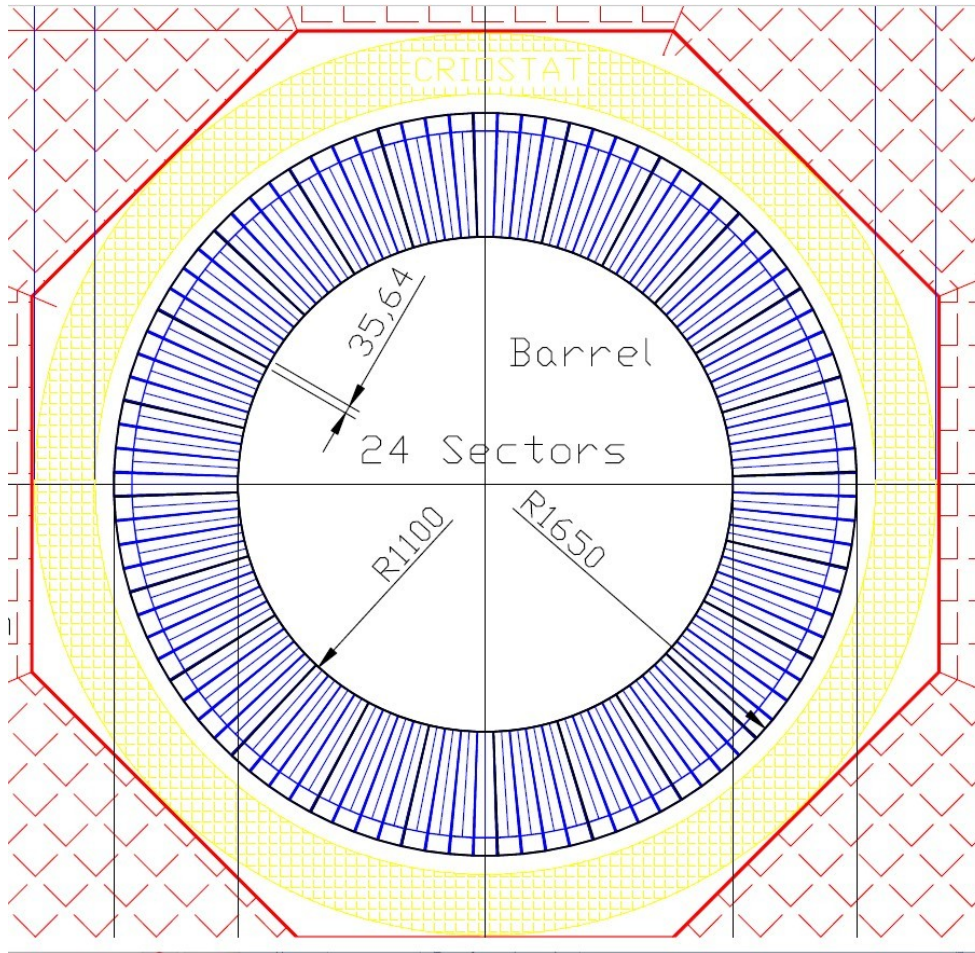
**Oleg Gavrishuk, Laboratory of High Energy Physics, Dubna,  
Russia**

- 1. ECAL position inside of Cryostat**
- 2. ECAL New Sizes corrected in 2023**
- 3. Test results with new SiPm EQR15 11-6060D-S**
  - 1. New Sipm testing results**
  - 2. EC prototype cells 40x40 Cosmic test**
- 4. Matrix form for new scintillator production (40x40x1.5 mm<sup>3</sup>)**
- 5. End Cup part of 256 cells plan to produce during of 2024**

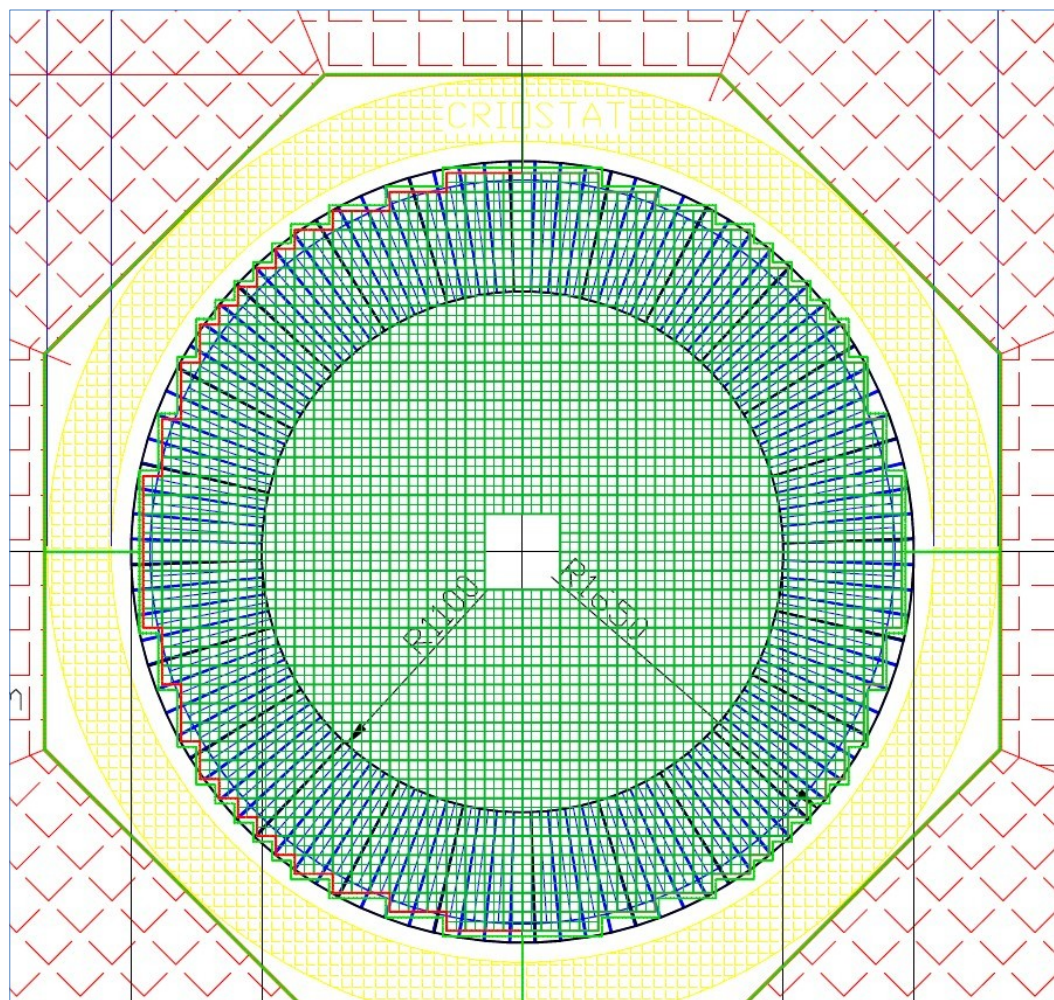
# ECAL with New Sizes in 2023



# ECAL with New Sizes in 2023



# ECAL composition with New Sizes in 2023



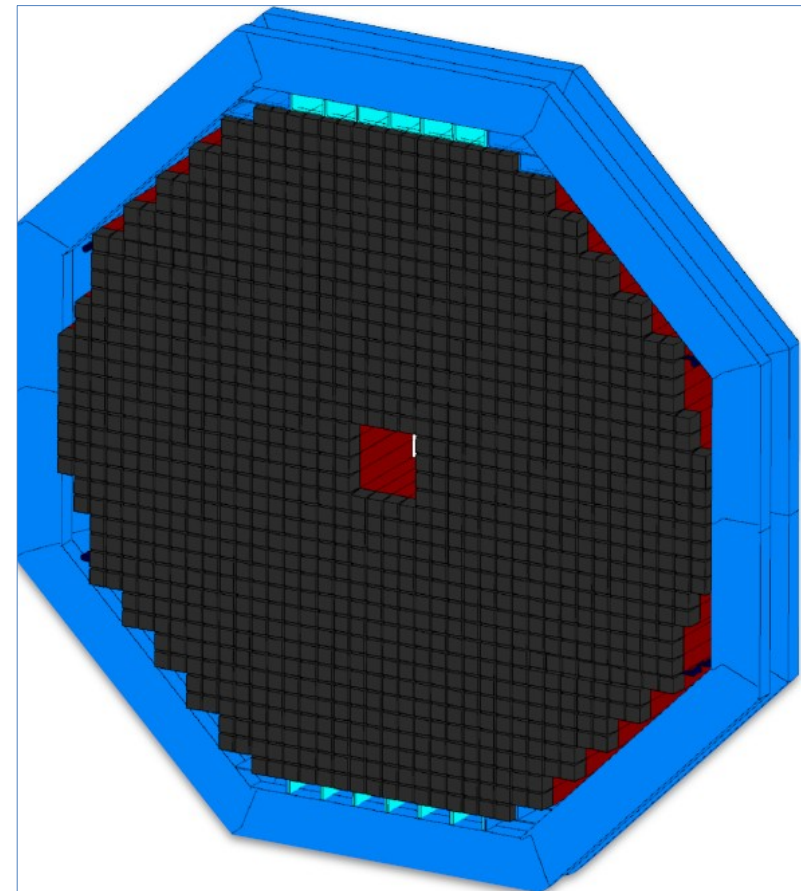
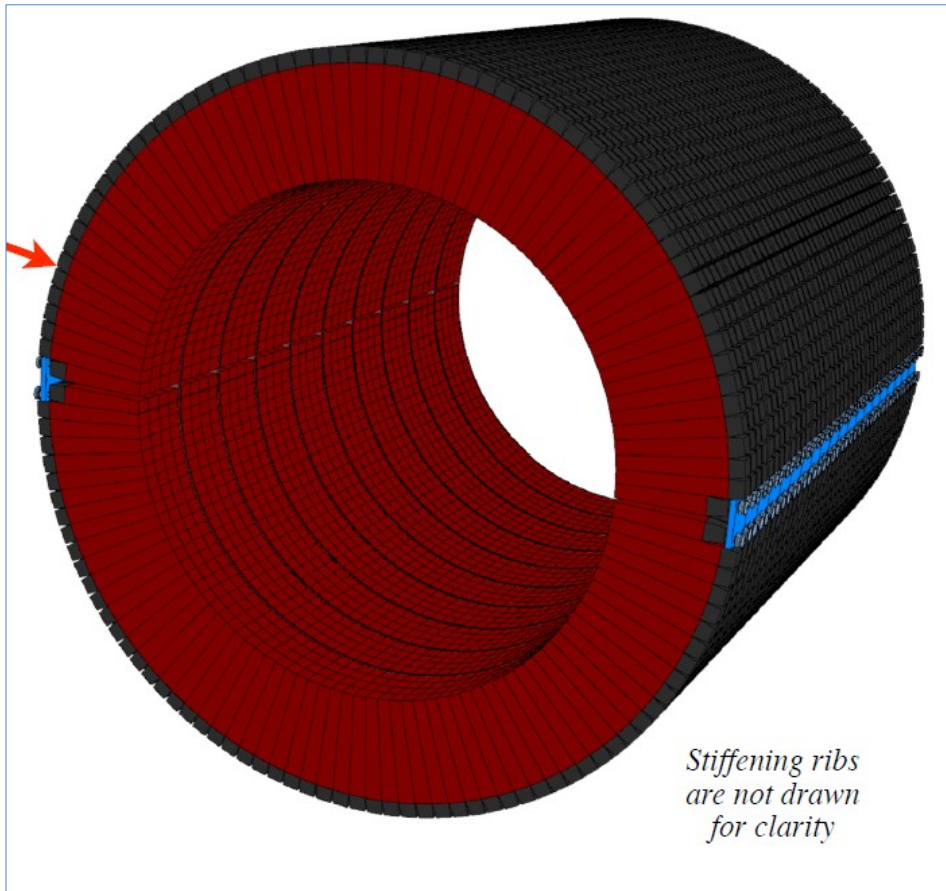
## Barrel :

1. 10 Rings - 1536 cells/Ring
2. Total Cells - 15360
3. ADC64 - 240
4. 16ch Amplifiers - 960
5. Power units - 24
6. Weight - 38.4 tonn

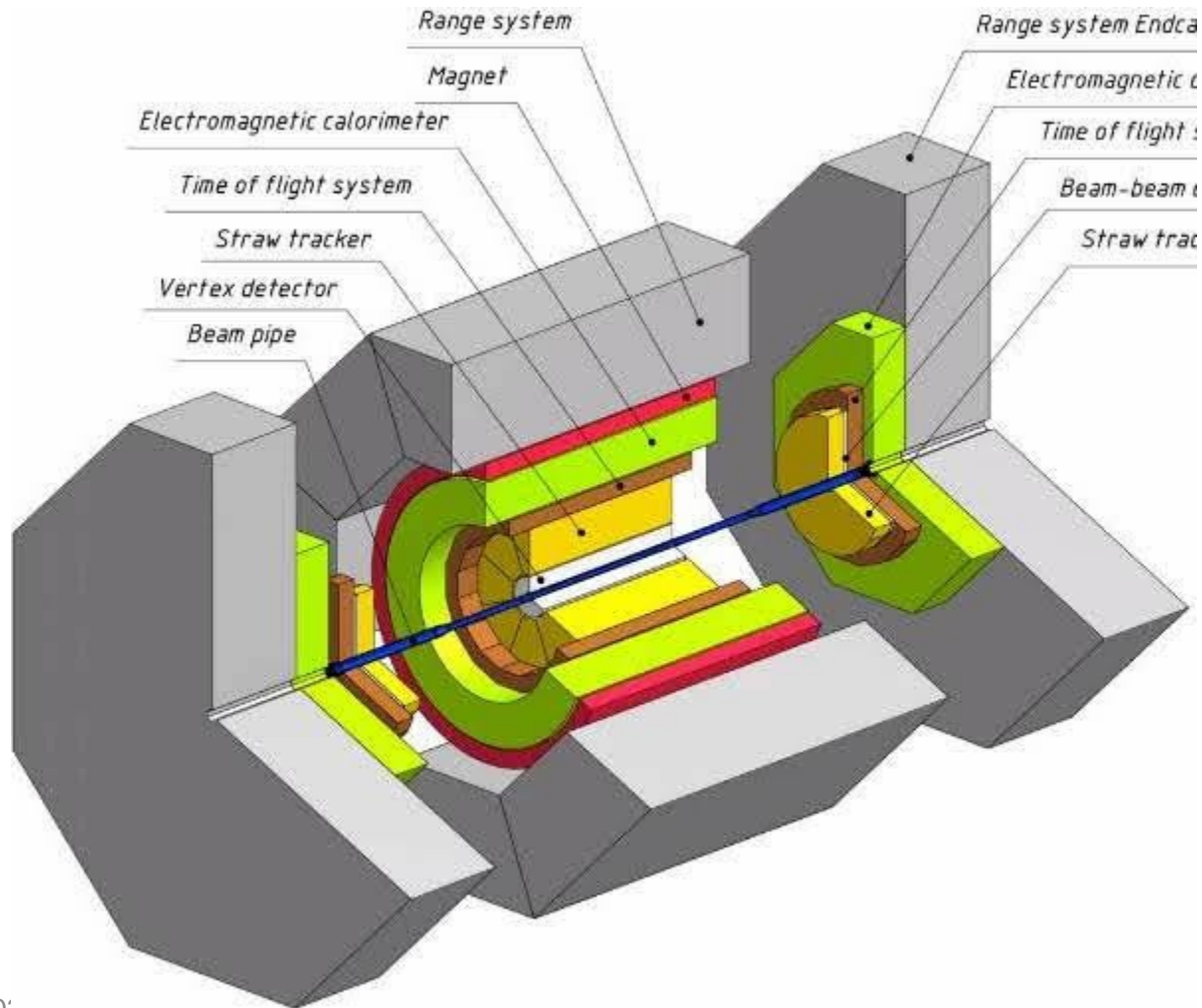
## 2 END CUP:

1. Cells - 5136 / per End Cup
2. Total cells - 10272
3. ADC64 - 160
4. 16ch Amplifiers - 642
5. Power units - 20
6. Total Weight - 25.6 ton

# ECAL 3D View Barrel and Cup parts



# ECAL integration inside of SPD



# Test results with cosmic particles



Cosmic Rays

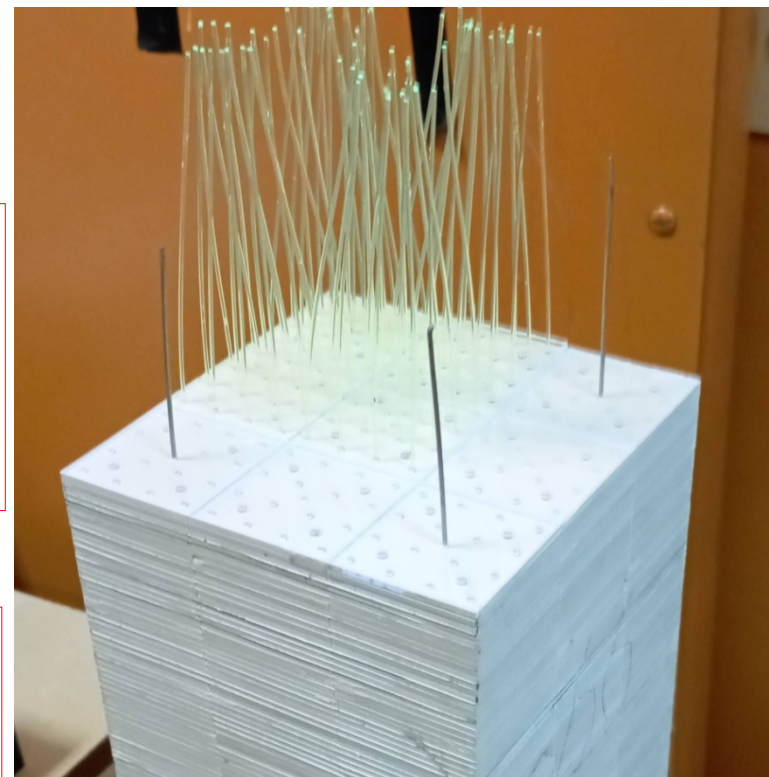
**Setup of 4 modules.**  
Each module consist from 9 cells of 4x4 cm<sup>2</sup>. Totally tested 36 cells.

## Sampling:

- 1.5 mm Scintillator
- 0.3 mm Lead
- 200 layers

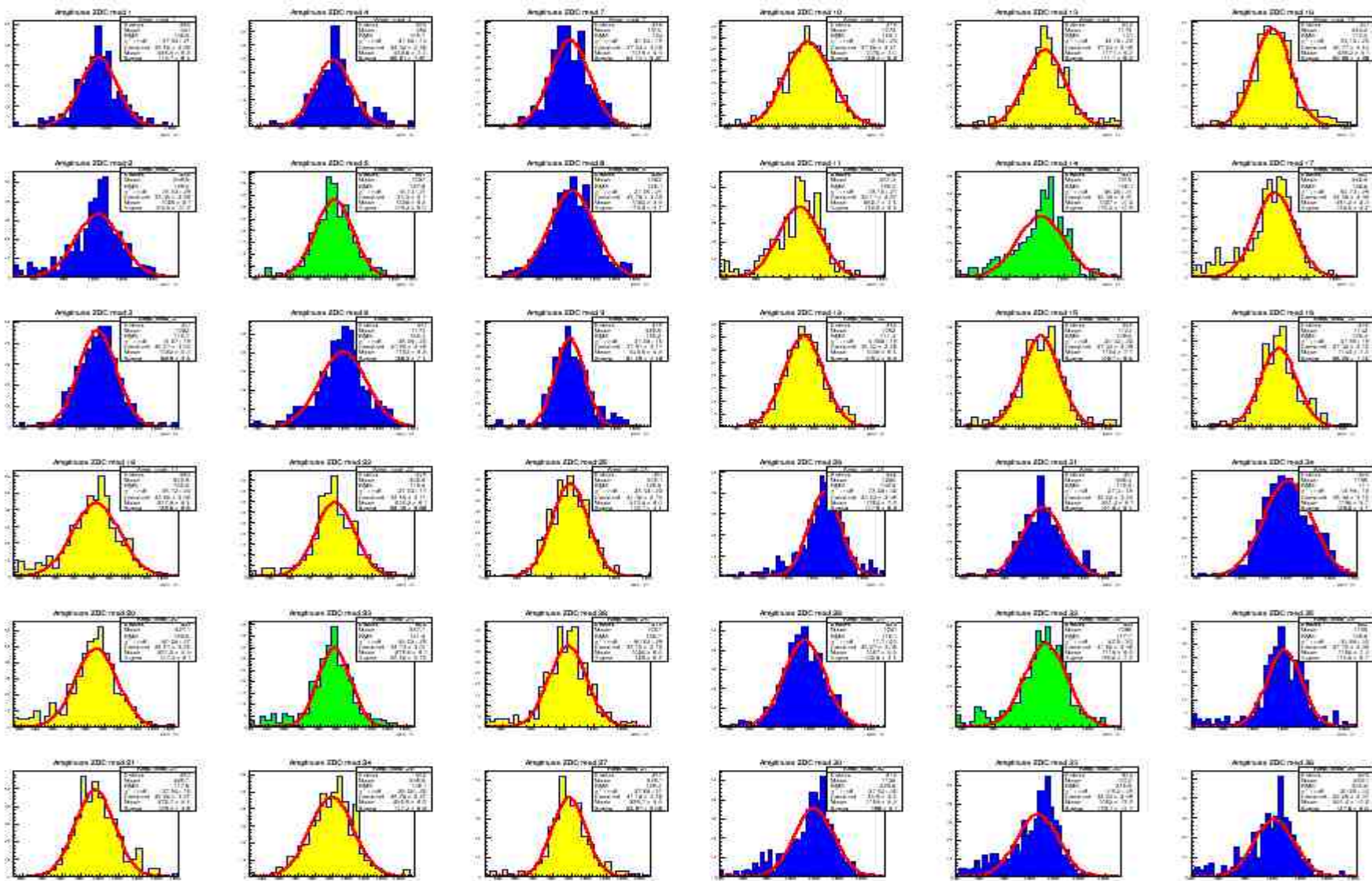
Scintillator composition:

- Polyesterene
- 1.5% Paterphenyle
- 0.04% POPOP



**Single Ecal module shown in assembling stage.**

It is visible 9 cells as 3x3 matrix with WLS fibers (16 per cell). Y11(200) diameter 1.0 mm was used.



MIP spectra from 36 Cells. Top view shown on picture Above. One hit/event  
 - applied selection criteria during analysis.

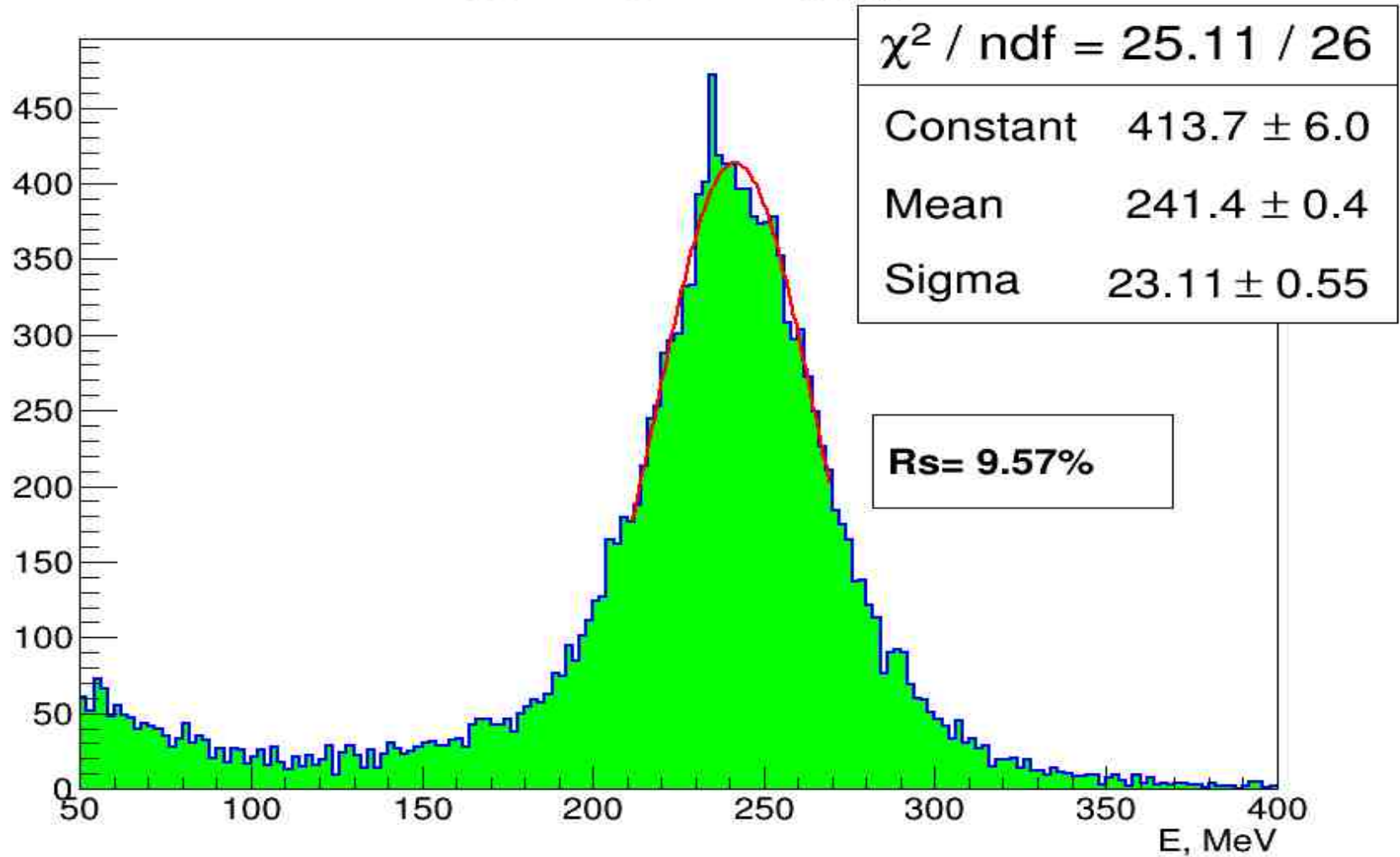
10/24/2023

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Calibration coefficients were found and normalized to 240 MeV.

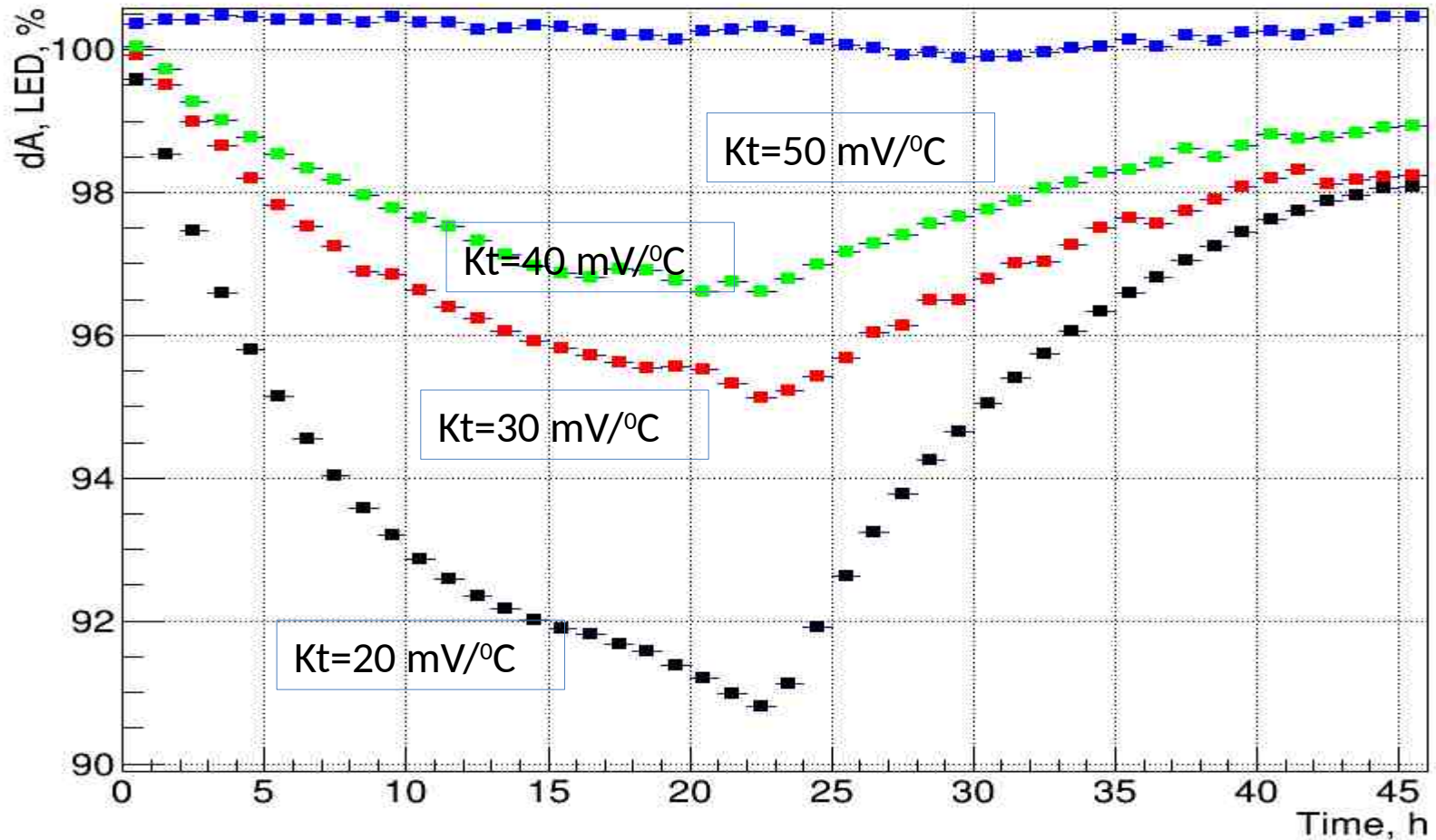


# Sum ECAL Energy



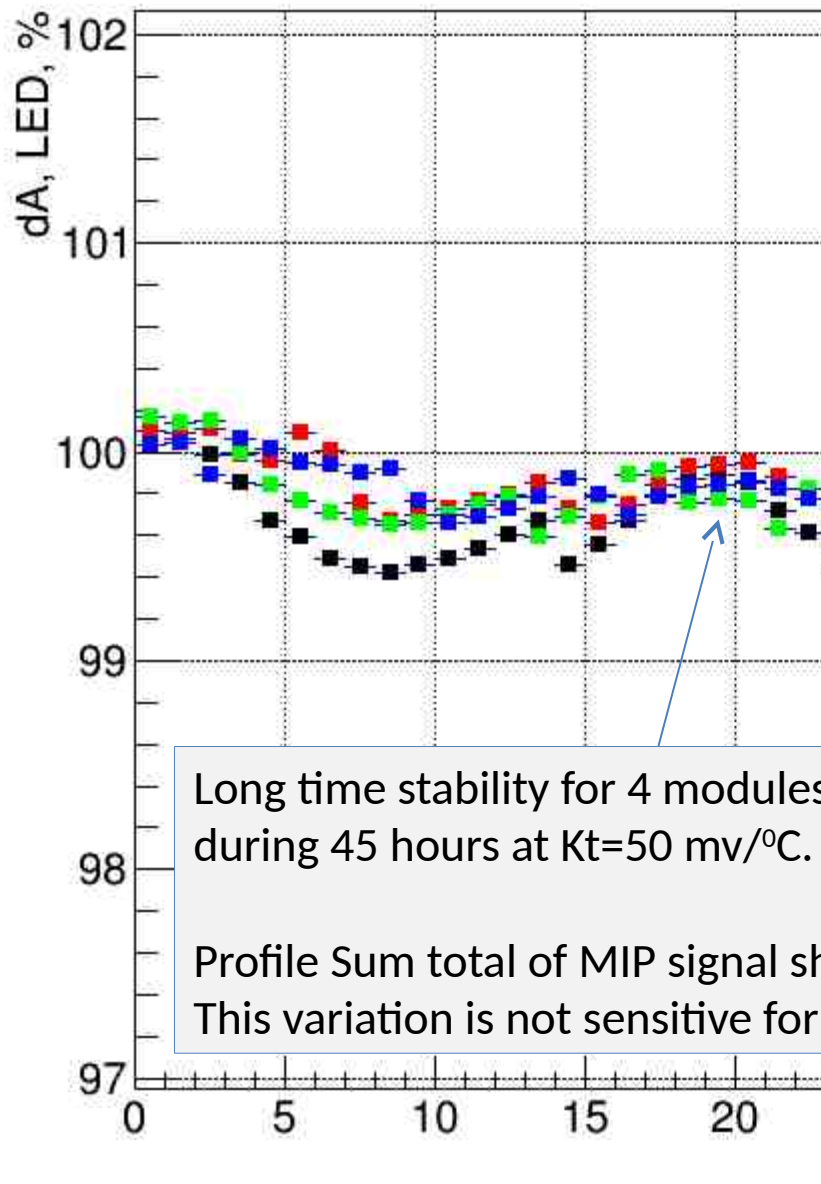
MIP spectra from 36 Cells as Total Sum take in account the Calibration coefficients normalized to 240 MeV. These Energy resolution corresponded to MC

## Profile\_LED\_1\_vs\_Evt\_with\_Temp\_compensation

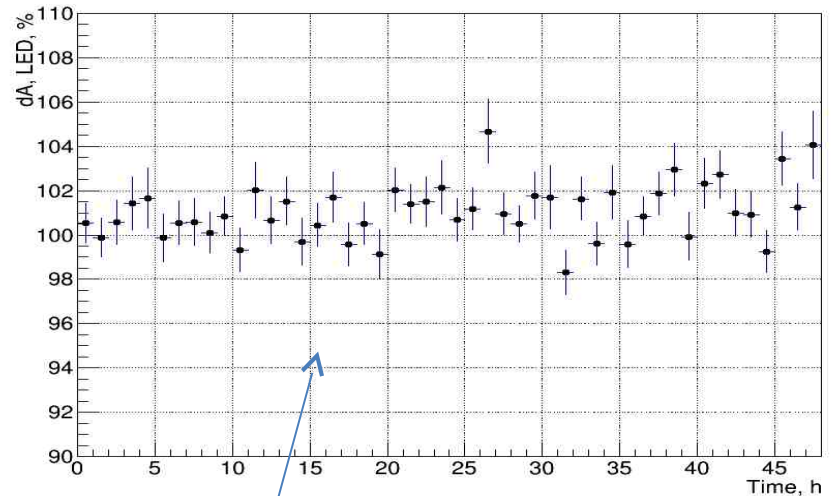


Test of long time Stability was done with different Kt for individual module.  
The temperature variation from 20 to 30 °C per day was applied.

### Profile\_LED\_1\_vs\_Evt



### Profile\_Sumtot\_vs\_Evt



Long time stability for 4 modules shown +/-0.5% LED signal variation during 45 hours at  $Kt=50 \text{ mv}/^{\circ}\text{C}$ .

Profile Sum total of MIP signal shown ~1% variation during 45 hours. This variation is not sensitive for MIP spectra with 9% resolution.

# NDL SiPm Series EQR15

## 11-6060D-S

[www.ndl-sipm.net/PDF/Datasheet-EQR15.pdf](http://www.ndl-sipm.net/PDF/Datasheet-EQR15.pdf)

NDL (Novel Device Laboratory, Beijing) <http://www.ndl-sipm.net/indexeng.html>

# NDL SiPM Series EQR15

## 11-6060D-S

[www.ndl-sipm.net/PDF/Datasheet-EQR15.pdf](http://www.ndl-sipm.net/PDF/Datasheet-EQR15.pdf)

- For a conventional SiPM, the quenching resistors are usually fabricated on the surface, and used to connect all APD cells to trace metal lines. In contrast, NDL SiPM employs intrinsic epitaxial layer as the quenching resistors (EQR), and uses a continuous silicon cap layer as an anode to connect all the APD cells. **As a result, the device has more compact structure and simpler fabrication technology, allows larger micro cell density (larger dynamic range) while retaining high photon detection efficiency (PDE).**
- Для обычного SiPM гасящие резисторы обычно изготавливаются на поверхности и используются для соединения всех ячеек APD с металлическими линиями. Напротив, NDL SiPM использует собственный эпитаксиальный слой в качестве гасящих резисторов (EQR) и использует непрерывный слой кремния в качестве анода для соединения всех ячеек APD. **В результате устройство имеет более компактную структуру и более простую технологию изготовления, позволяет увеличить плотность микроячеек (большой динамический диапазон) при сохранении высокой эффективности детектирования фотонов (PDE).**
- NDL (Novel Device Laboratory, Beijing) <http://www.ndl-sipm.net/indexeng.html>



# EQR15 Series SiPMs

Specifications subject to change without notice



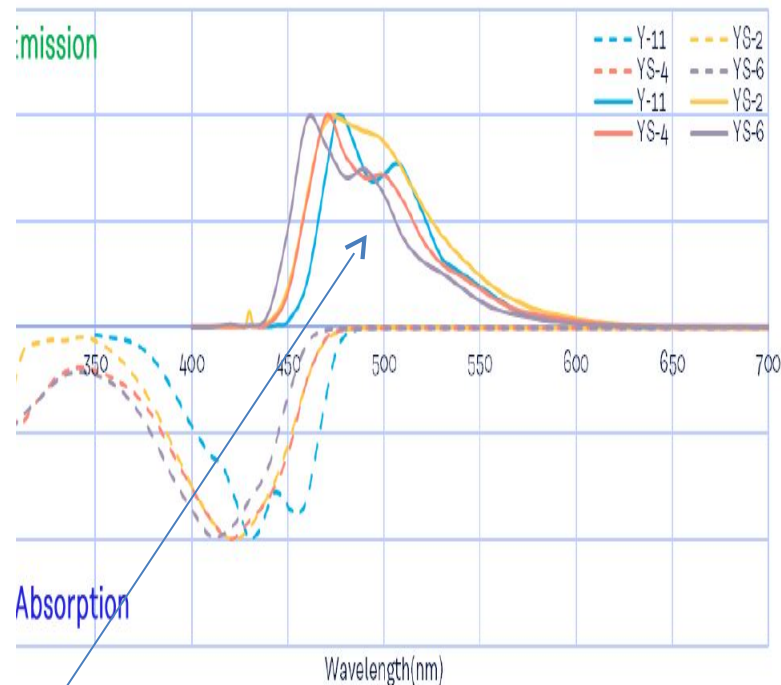
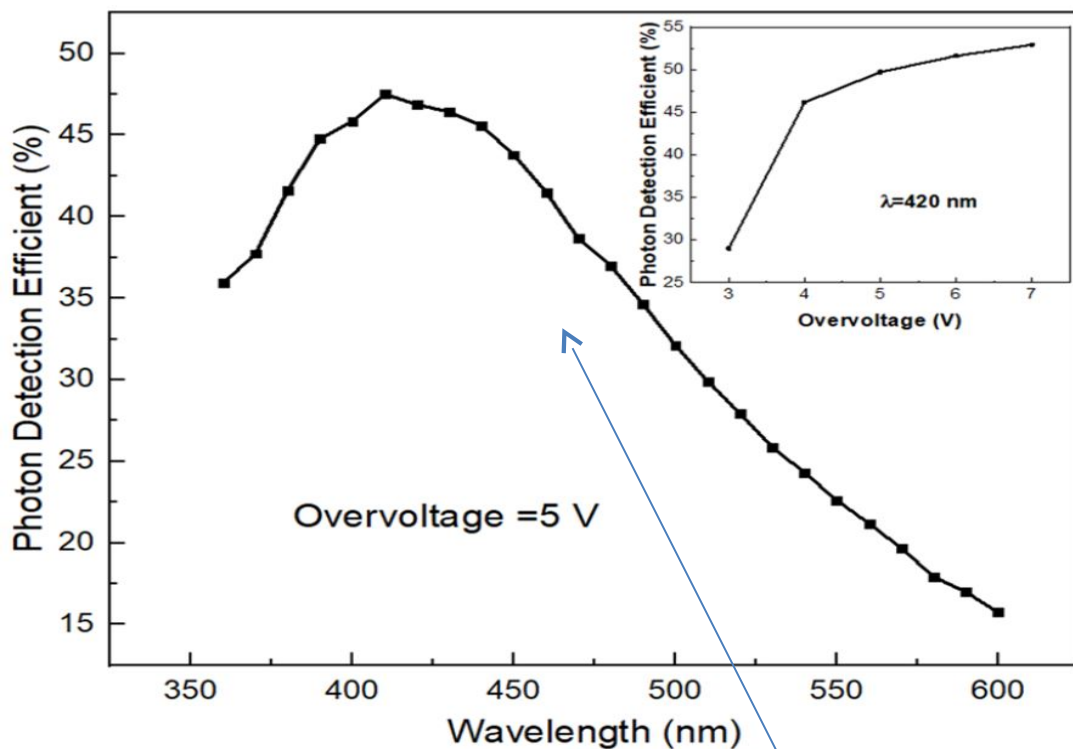
| Type                                | EQR15<br>11-1010D-S              | EQR15<br>11-3030D-S              | EQR15<br>11-6060D-S              | EQR15<br>22-1313D-S              |
|-------------------------------------|----------------------------------|----------------------------------|----------------------------------|----------------------------------|
| Effective Pitch                     | 15 $\mu\text{m}$                 |                                  |                                  |                                  |
| Element Number                      | 1 $\times$ 1                     |                                  |                                  | 2 $\times$ 2                     |
| Active Area                         | 1.0 $\times$ 1.0 mm <sup>2</sup> | 3.0 $\times$ 3.0 mm <sup>2</sup> | 6.0 $\times$ 6.0 mm <sup>2</sup> | 1.3 $\times$ 1.3 mm <sup>2</sup> |
| Micro-cell Number                   | 4444                             | 40000                            | 160000                           | 7396                             |
| Typical Breakdown Voltage ( $V_B$ ) | 30 V                             |                                  |                                  |                                  |
| Temperature Coefficient for $V_B$   | 28 mV/ $^{\circ}\text{C}$        |                                  |                                  |                                  |
| Recommended Operation Voltage       | $V_B + 8 \text{ V}$              |                                  |                                  |                                  |
| Peak PDE @ 420nm                    | 45 %                             |                                  |                                  |                                  |
| Gain                                | $4.0 \times 10^5$                |                                  |                                  |                                  |
| Dark Count Rate (DCR)               | 250 kHz / mm <sup>2</sup>        |                                  |                                  |                                  |
| Terminal Capacitance                | 5.6 pF / mm <sup>2</sup>         |                                  |                                  |                                  |

Above parameters is measured at their recommended operation voltage and 20  $^{\circ}\text{C}$ , and it can operate at 77 K.



# EQR15 Series SiPMs

Specifications subject to change without notice



Photon Detection Efficient (PDE) correspond to WLS Emission spectra of Y11. PDE close to flat maximum about 45% at 6-7 Overvoltage.

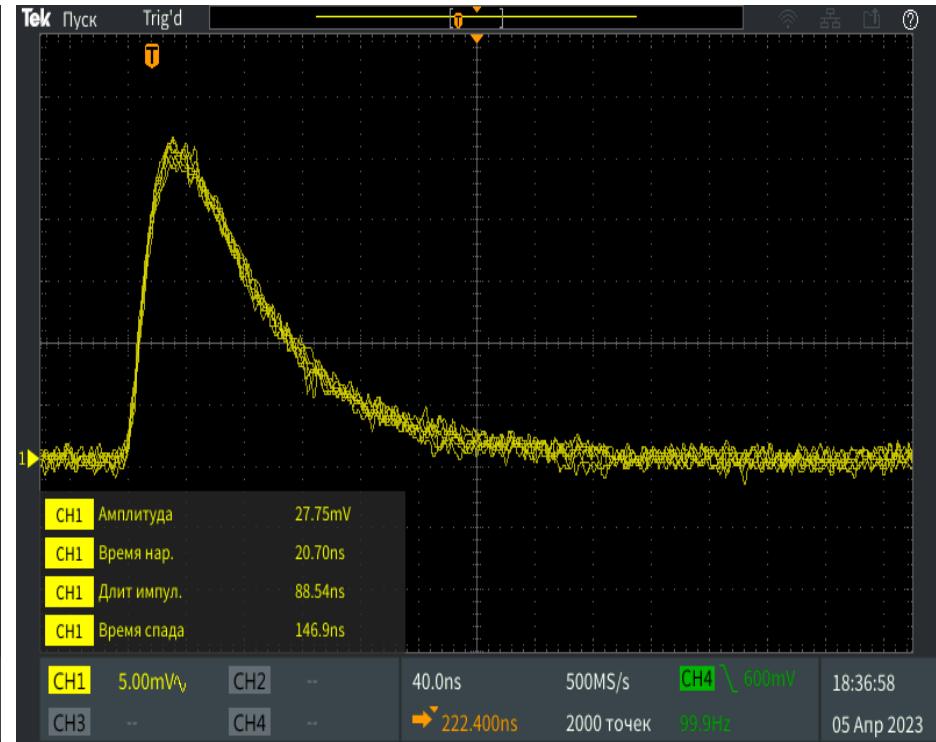
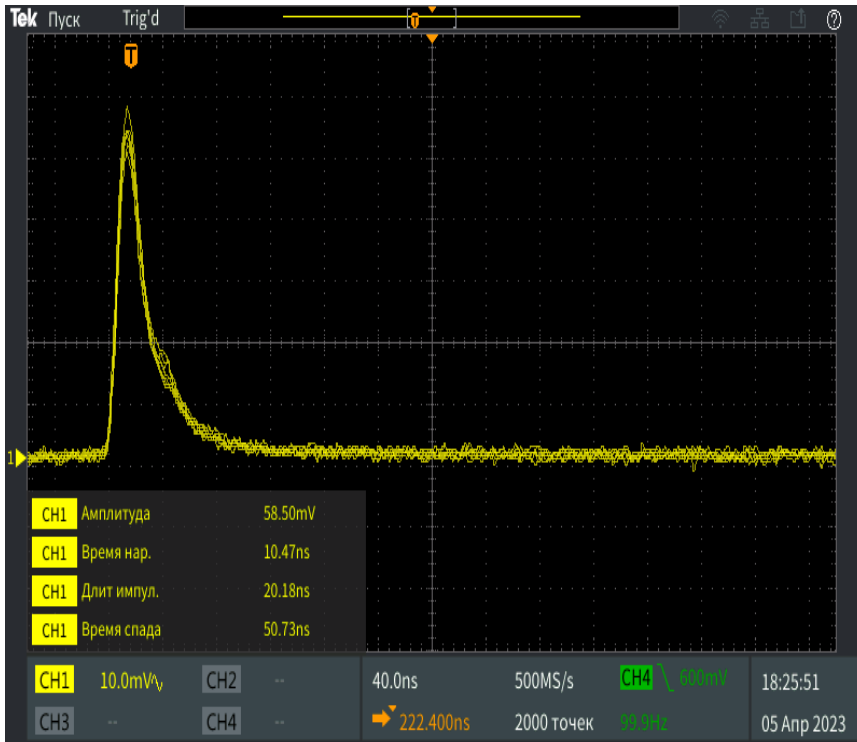


# EQR15 Series SiPMs

Specifications subject to change without notice



Pulse shape of SiPm with 15  $\mu$  pitch and 6x6 mm<sup>2</sup> size



EQR-15-60  
Front – 10 ns  
Length – 20 ns

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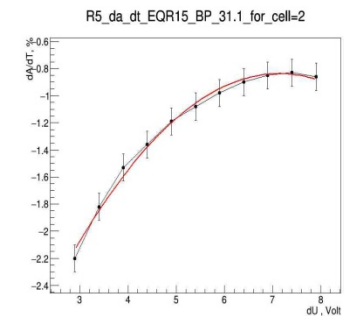
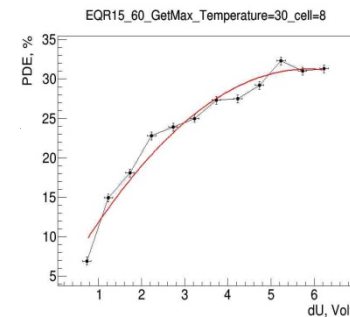
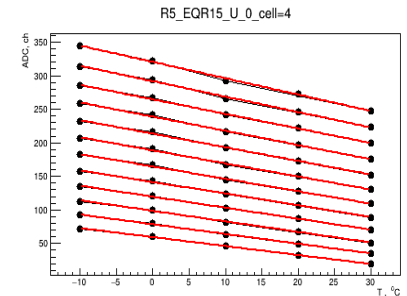
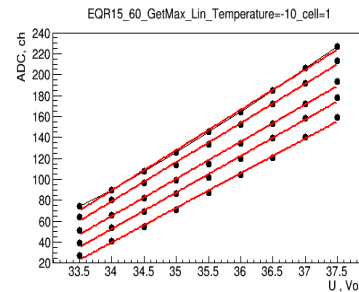
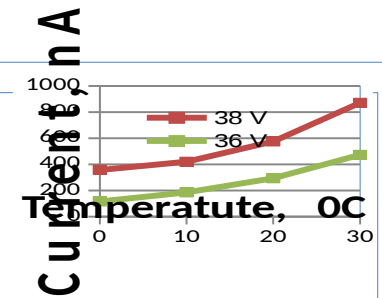
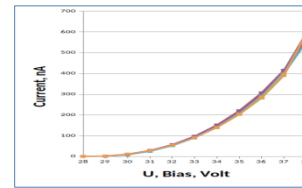
HAMAMATSU S14160-6015  
Front – 21 ns  
Length – 89 ns

16

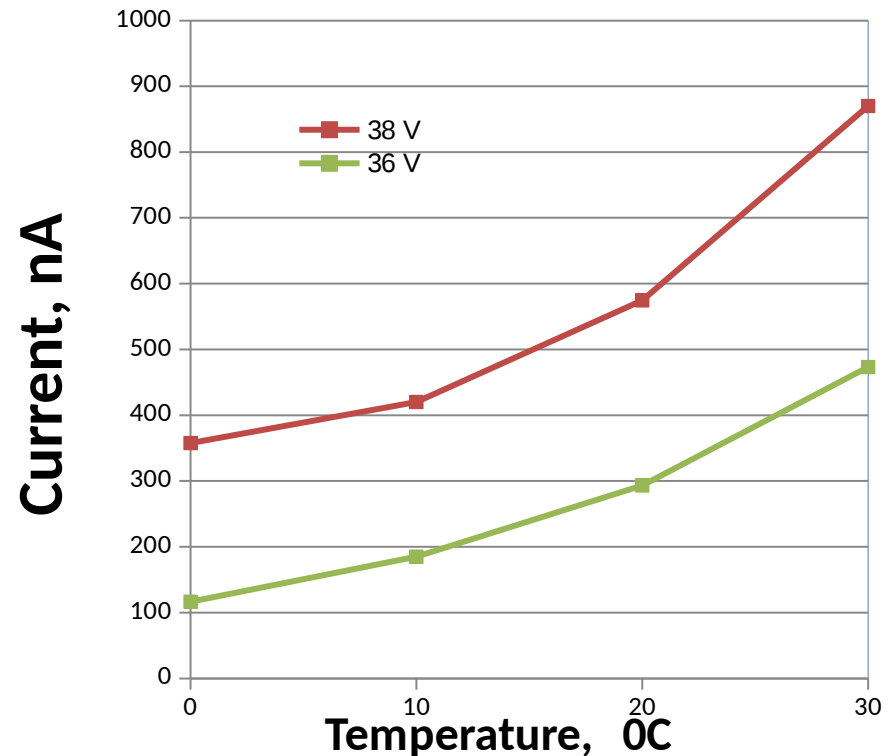
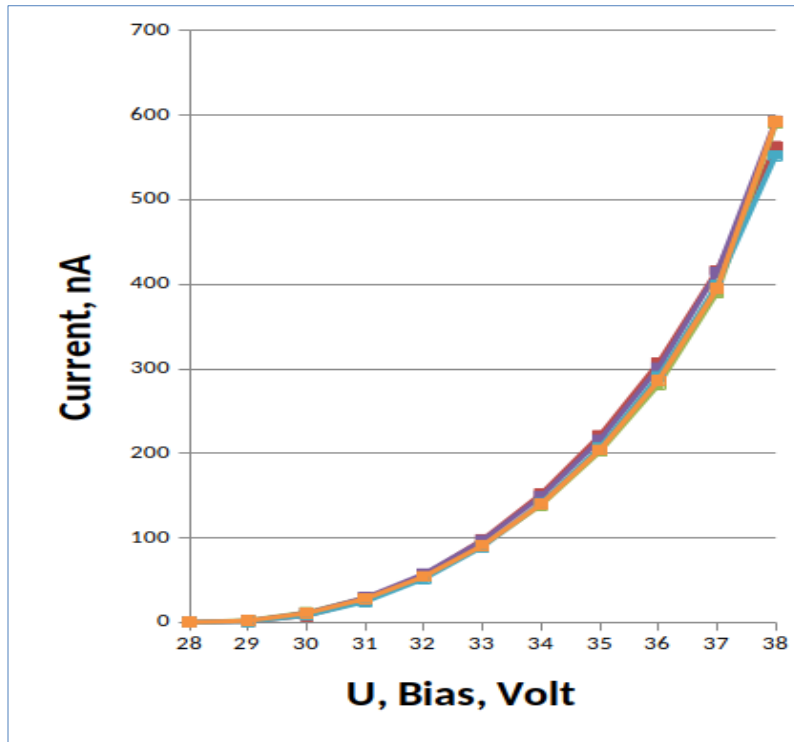


# SiPm test Results

- Dark Current measurements
- Gain vs Overvoltage:  $dA/dU$
- Gain vs Temperature:  $dA/dt$
- PDE vs Overvoltage
- Operation Volt. how to select it
- Temperature stability studies



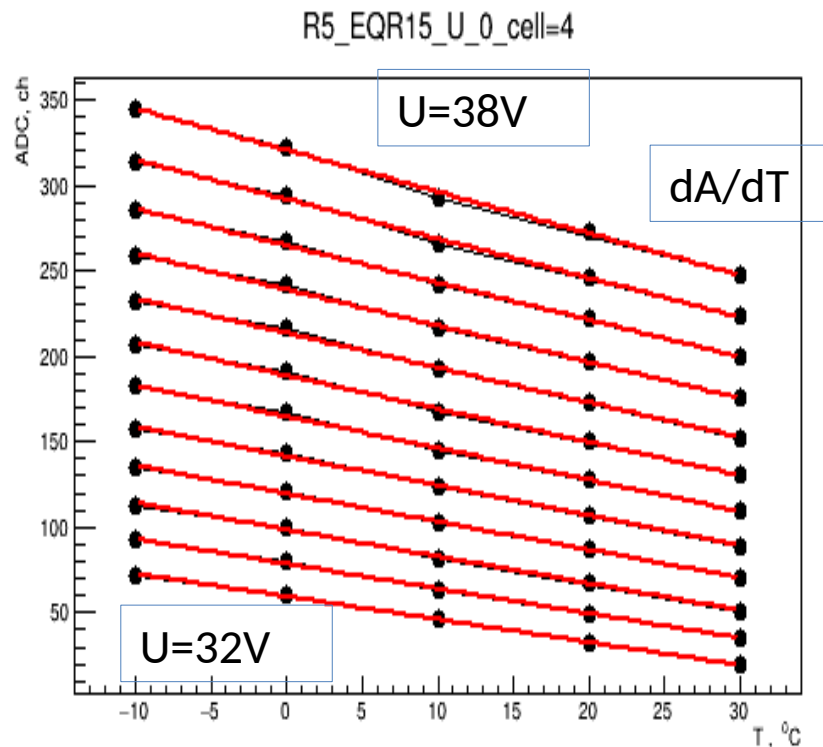
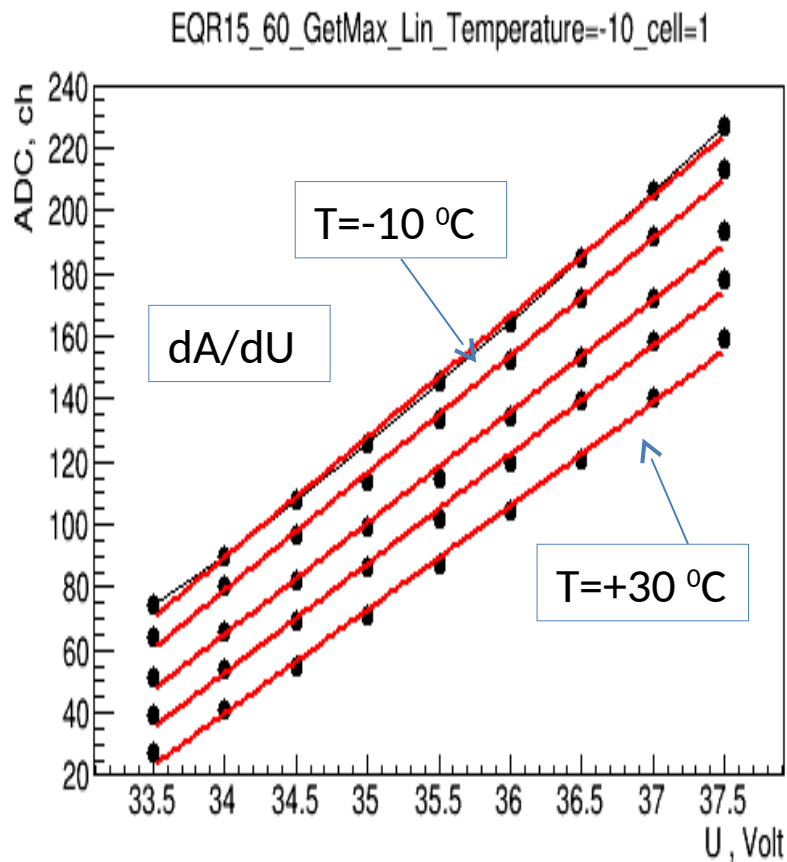
# EQR15-60 Dark Current vs Bias voltage and its temperature dependences around operate Voltage



Dark Current vs Operation Bias (36-37 V) at room temperature (20 °C) is equal to 300-400 nA. Its are corresponded to the factory data and is similar HAMAMATSU too.

Gain vs Overvoltage allow obtain:  
slope= $dA/dU$  vs  $U$

Gain vs Temperature allow obtain:  
slope= $dA/dT$  vs  $T$

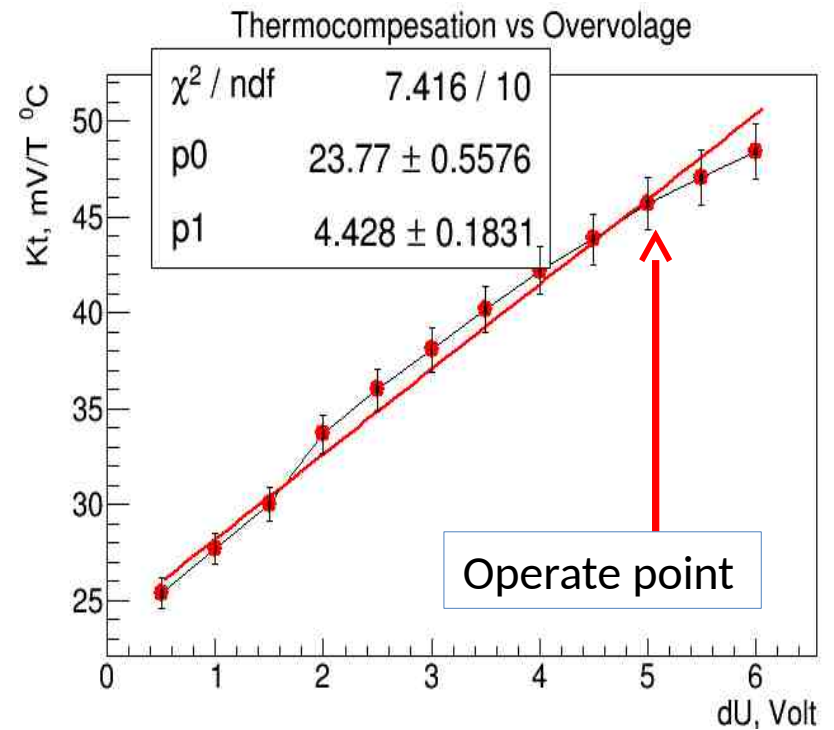
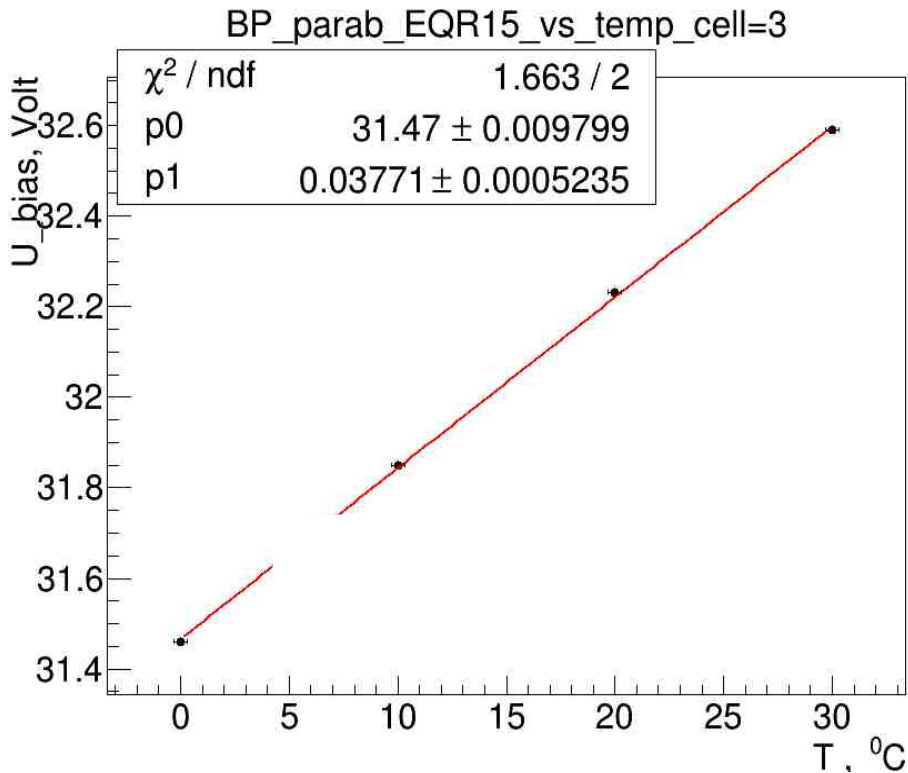


$$K_t = dU/dT = dA/dT / dA/dU$$

The thermal stabilization coefficient ( $K_t$ ) was defined as the ratio of the slope  $dA/dT$  to the slope  $dA/dU$  depending on the applied bias.

Break Point (Bp) was defined as extrapolation point of  $dA/dU$  to zero. Take assumption his linear behavior from Temperature we find that  $Bp=32$  V at  $20^{\circ}\text{C}$ .

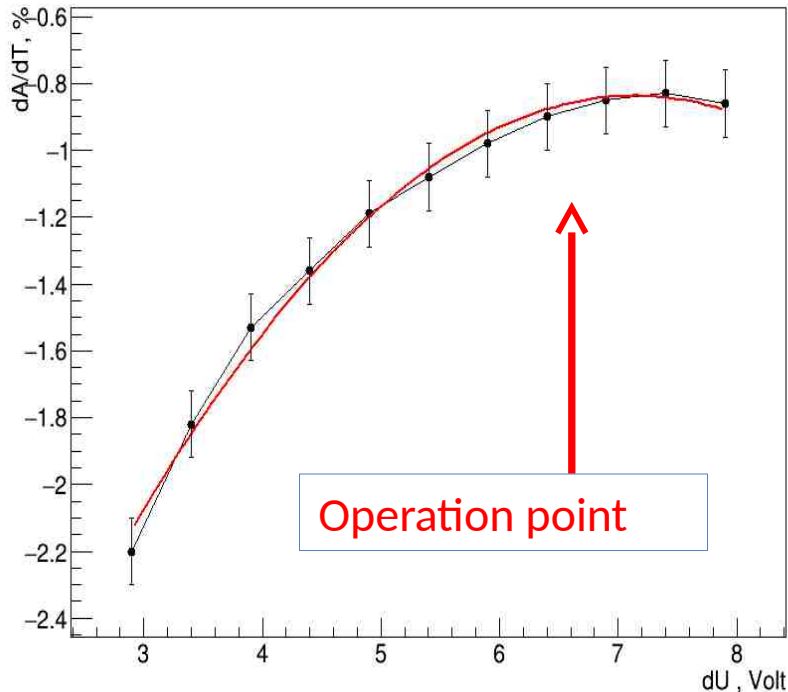
$K_t=dU/dT=dA/dt/dA/dU$  fom previous slides we find that dependence from Overvoltage has linear behavior and equal to  $\sim 50$   $\text{mV}/^{\circ}\text{C}$  at Operation point 5.5 V.



# Temperature sensitivity vs dU

## dA/dT vs dU

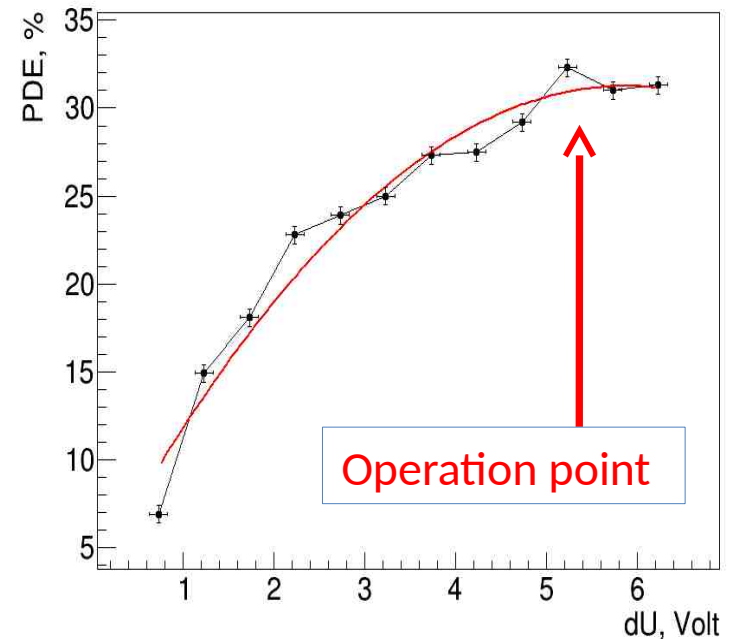
R5\_da\_dt\_EQR15\_BP\_31.1\_for\_cell=2



# Photon Detection Efficient vs dU

## PDE vs dU

EQR15\_60\_GetMax\_Temperature=30\_cell=8

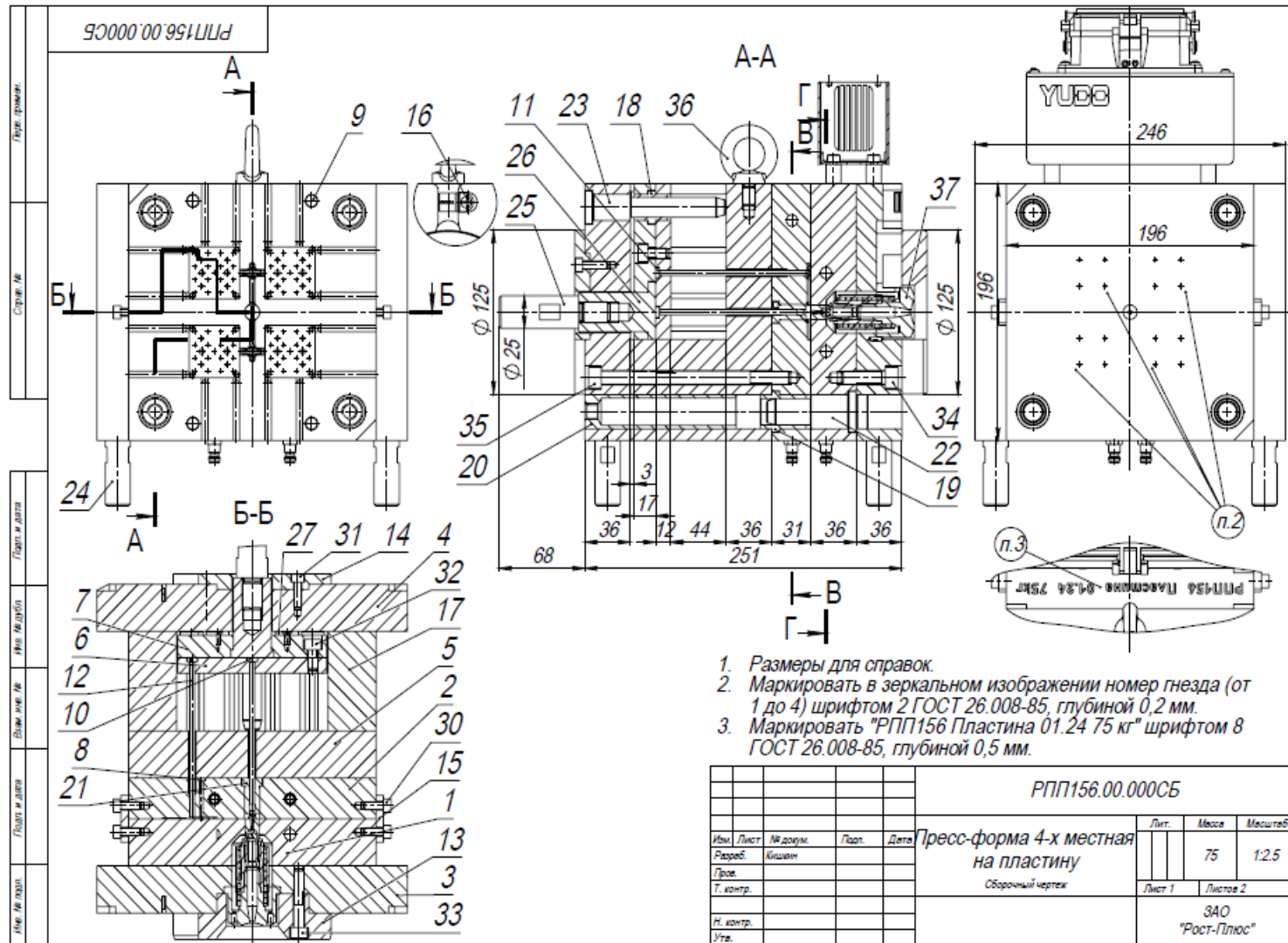


Operation point was found at  $dU=6.5$  V take in account that:

1.  $dA/dT$  and PDE – has Plato in  $dU$ .
2.  $dA/dT$  has minimal value  $\sim 1\%/^{\circ}\text{C}$ , PDE close to maximal value  $\sim 32\%$ .

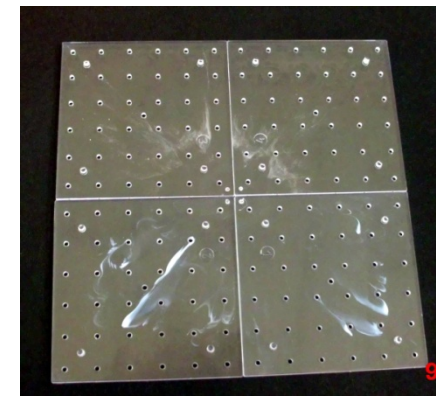
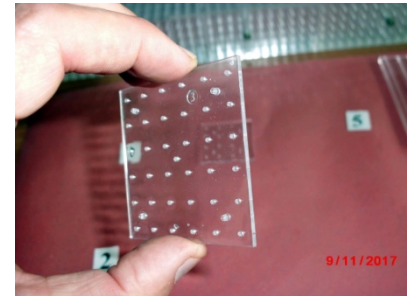
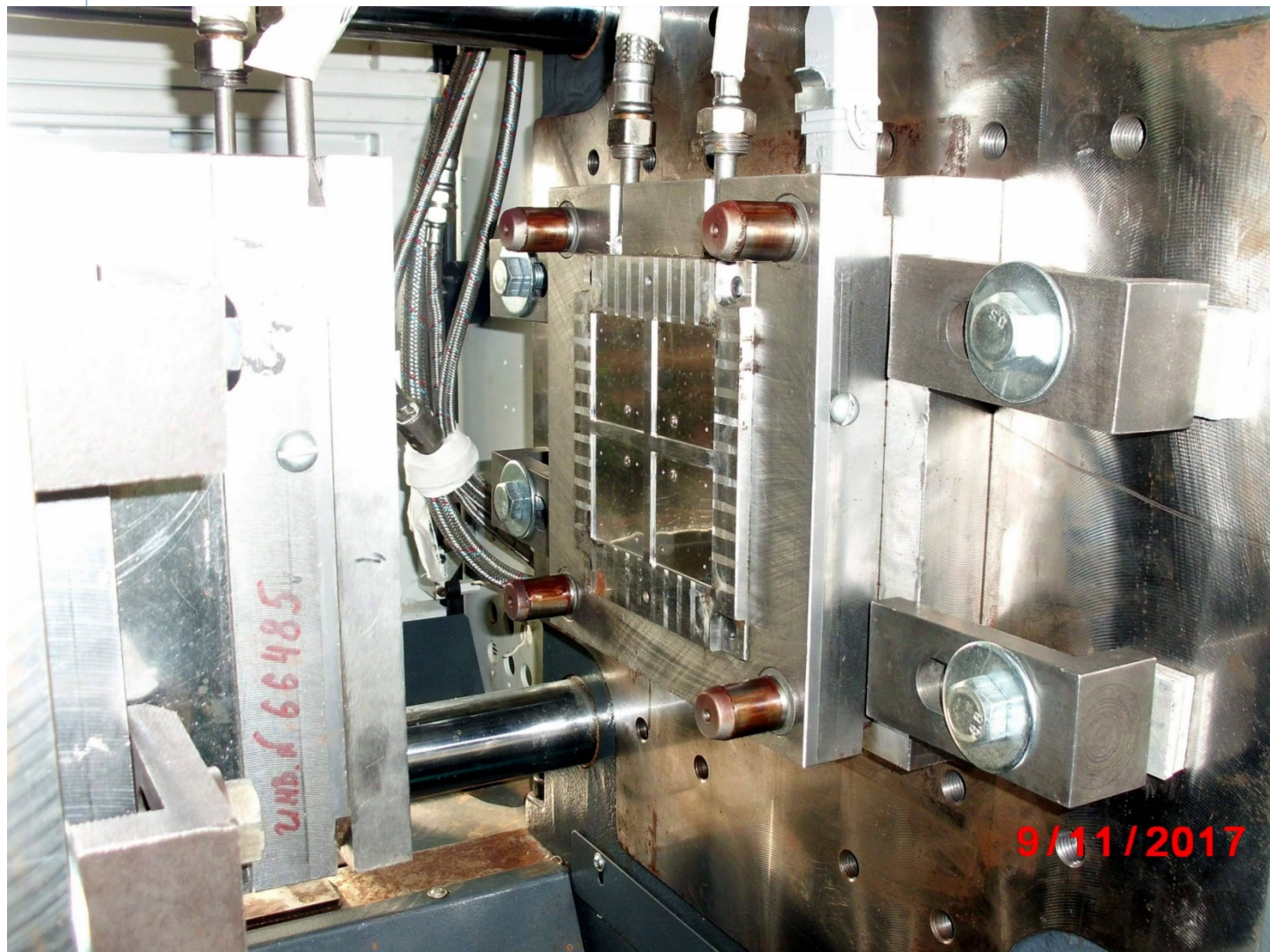
# Matrix form drawing 2023 for scintillator production (40x40x1.5 mm<sup>3</sup>)

Shown t drawing of 4 sets form to produce 4 scintillator plates per one cycle.  
Matrix form it is a special setup for molding by pressure technology.



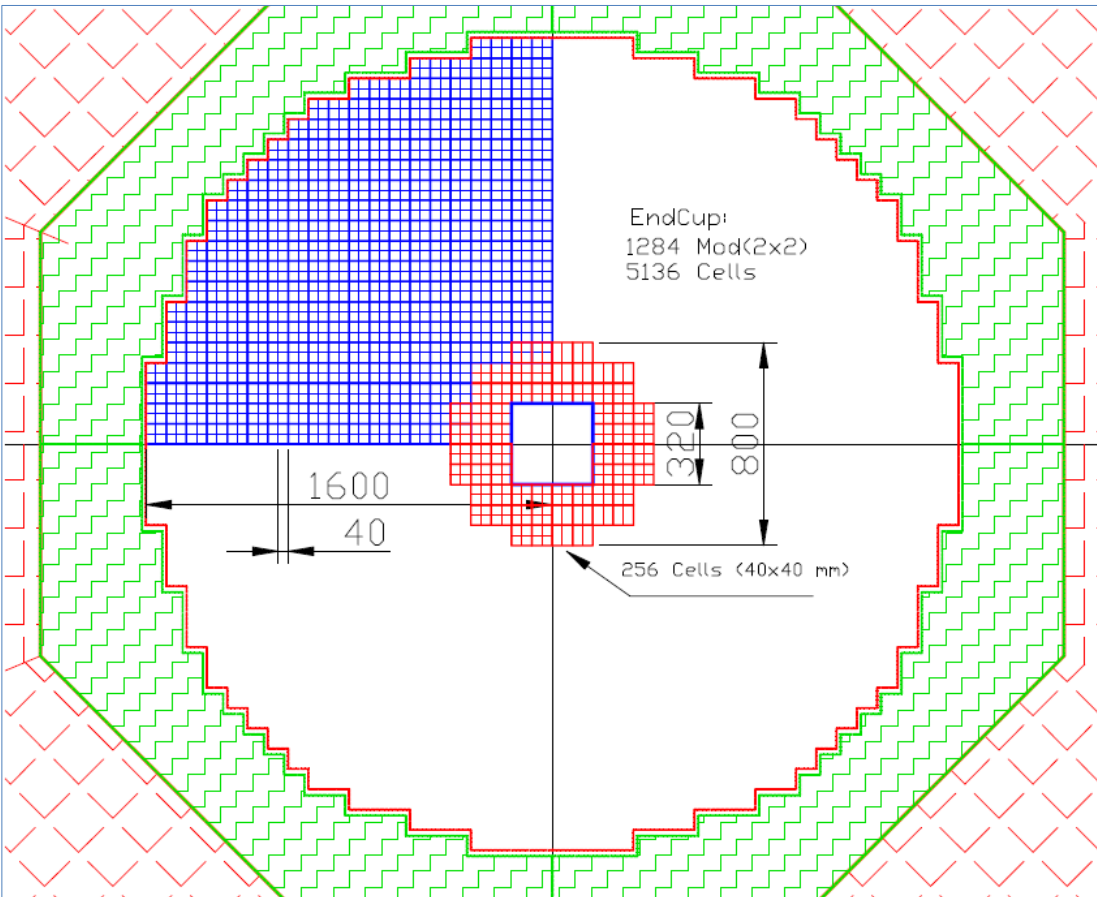
## 4-Set Matrix form for scintillator production

Matrix form is special setup for molding by pressure technology. It allow produce the scintillators from granulated polystyrene with doppands. 4 set form produce 4 scintillators plates of  $40 \times 40 \times 1.5 \text{ mm}^3$  per 1 minute.



# End Cup for SPD with new scintillator to be produced in 2024 via 256 cells of 40x40 mm<sup>2</sup>

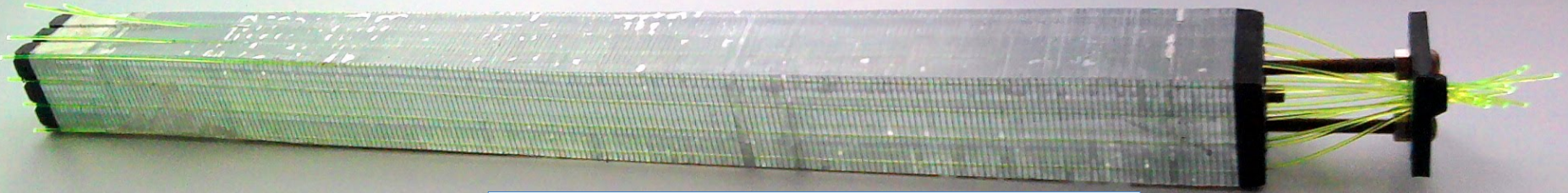
**It is I-st stage possible setup to estimate the particles flow at NICA**



This Figure shows in red 64 modules, consisting of 4 cells each. The weight of this assembly is 597 kg. This will require 130 kg of polystyrene, 465 kg of lead, as well as additives: 1.95 kg of P-terphenyl and 65 g. POPOP, and 2000 meters WLS fiber type Y-11. **It is 1/20 part of End Cup and taken time of 36 Days to prepared 51200 Stint. plates.** To read this setup, we need four ADC64 - 64-channel amplitude encoders, as well as 16 boards of 16-channel amplifiers and bias voltage regulators.

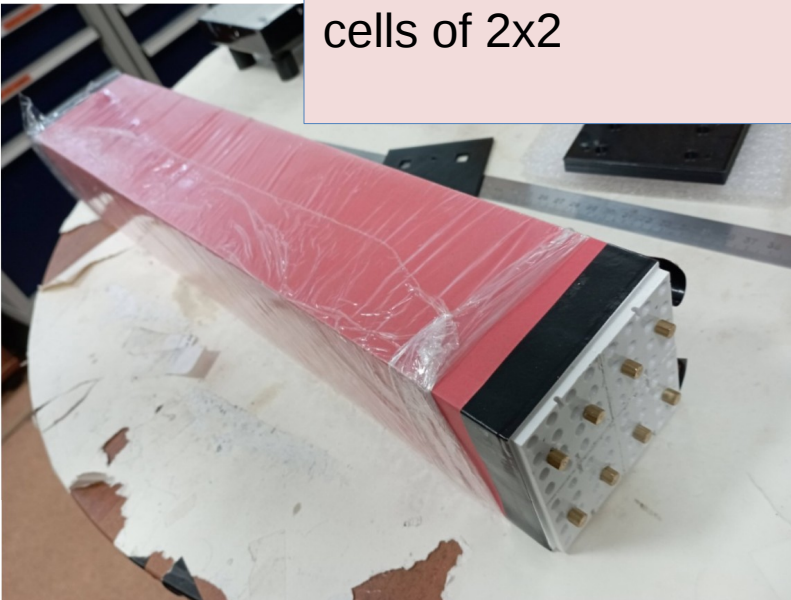


# End Cup for SPD with new scintillator to be produced in 2024 via 256 cells of 40x40 mm<sup>2</sup>

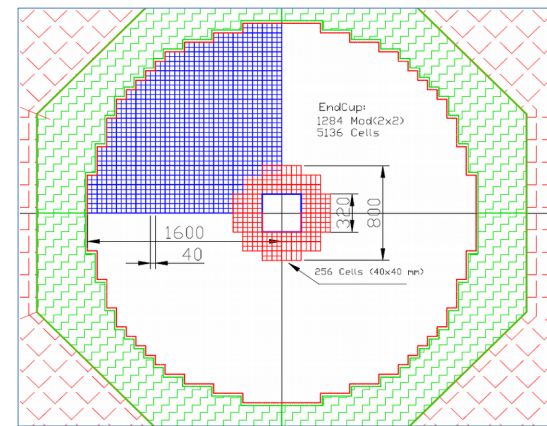


Single Cell 40x40 mm<sup>2</sup>

One Module setup consist from 4 cells of 2x2



**In red** is shown 64 Modules, consisting from 4 cells each of 2x2.



# Conclusions

1. New ECAL geometry was designed in 2023
2. SiPm EQR15-60 China production were studied
3. New ECAL setup with cell size  $4 \times 4 \text{ cm}^2$  assembled
4. ECAL test in cosmic rays was done
5. Matrix form for new scintillator production should be ready in end of 2023
6. New scintillator production will start in beginning of 2024

**70 лет ЛФВЭ**

**NISA  
2023**

**ЭФЛАН 1953 -  
ЛВЭ 1956**



# End of Report

*Thanks for attention to All*